# MSKSEMI 美森科













ESD

TV

TSS

MOV

GDT

PIFD

XC6219

**Product specification** 





## **General Description**

The XC6219 series are highly accurate, low noise, CMOS LDO Voltage Regulators. Offering low output noise, high ripple rejection ratio, low dropout and very fast turn-on times, the XC6219 series is ideal for today's cutting edge mobile phone. Internally the XC6219 includes a reference voltage source, error a mplifiers, driver transistors, current limiters and phase compensators.

The output voltage is set by current trimming. Voltages are selectable in 100 mV steps within a range of 1.2V to 5.0V.

The XC6219 series is also fully compatible with low ESR ceramic capacitors, reducing cost and improving output stability. This high level of output stability is maintained even during fr equent load fluctuations, due to the excellent transient response performance and high PSRR achieved across a broad range of frequencies. The CE function allows the output of regulat or to be turned off, resulting in greatly reduced power consumption.

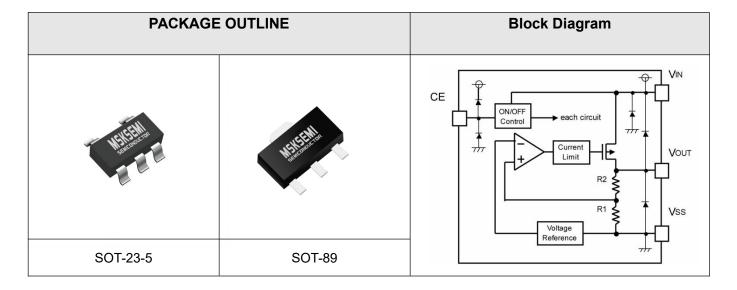
#### **Features**

- Low power consumption:40uA (Typ.)
- Low voltage drop:
  - 0. 12V@ 100mA@VOUT=3.3V(Typ.)
- Standby Mode: 0. 1uA
- Low temperature coefficient
- High input voltage (up to 8V)
- Output voltage accuracy: tolerance ±2%
- SOT23-5、SOT89package

## **Application**

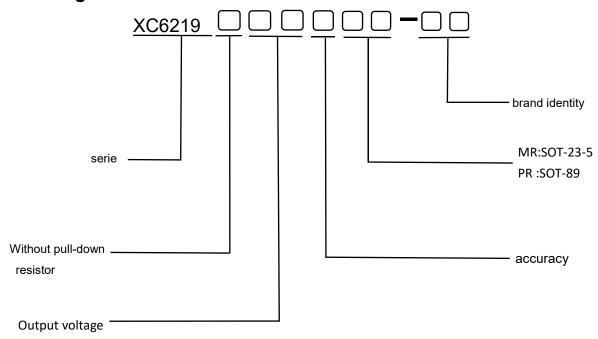
- Battery-powered equipment
- Communication equipment
- Mobile phones
- Portable games
- Cameras, Video cameras
- Reference voltage sources

#### **Reference News**





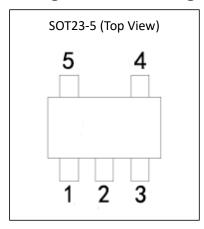
# **Ordering Information**



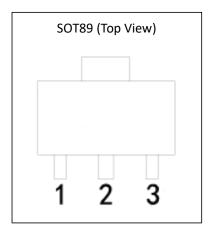
Item number	package	Output	Item number	package	Output
		voltage			voltage
XC6219B122MR-MS	SOT-23-5	1.2V	XC6219B122PR-MS	SOT-89	1.2V
XC6219B152MR-MS	SOT-23-5	1.5V	XC6219B152PRMS	SOT-89	1.5V
XC6219B182MR-MS	SOT-23-5	1.8V	XC6219B182PRMS	SOT-89	1.8V
XC6219B252MR-MS	SOT-23-5	2.5V	XC6219B252PRMS	SOT-89	2.5V
XC6219B282MR-MS	SOT-23-5	2.8V	XC6219B282PRMS	SOT-89	2.8V
XC6219B302MR-MS	SOT-23-5	3V	XC6219B302PRMS	SOT-89	3V
XC6219B332MR-MS	SOT-23-5	3.3V	XC6219B332PR-MS	SOT-89	3.3V
XC6219B362MR-MS	SOT-23-5	3.6V	XC6219B362PR-MS	SOT-89	3.6V



## Package and Pin assignment



PIN NUMBER	SYMBOL	FUNCTION	
1	VIN	Power Input Pin	
2	GND	Ground	
3	CE	Chip Enable Pin	
4	NC	No Connection	
5	VOUT	Output Pin	



PIN NUMBER	SYMBOL	FUNCTION
1	GND	Ground
2	VIN	Power Input Pin
3	VOUT	Output Pin

## **Absolute Maximum Ratings**

Supply Voltage -0.3V to 8V Storage Temperature .....-50C to 125C

Operating Temperature -40C to 85C

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

#### **Thermal Information**

Symbol	Parameter	Package	Max.	Unit
	Thermal Resistance (Junction to	SOT23-5	500	
Өла	Ambient) (Assume no ambient airflow, no heat sink)	SOT89	200	°C/W
Pp	Power Dissipation	SOT23-5	0.25	W
<b>P</b> D	1 owo. Dissipation	SOT89	0.5	VV

Note:PDismeasuredatTa=25℃

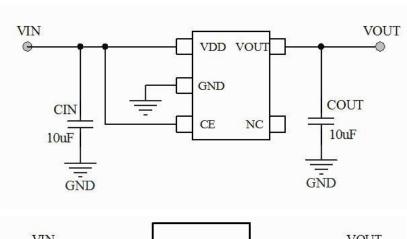


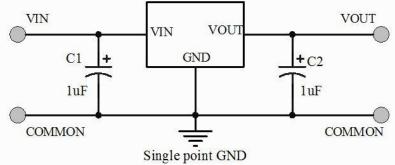
## **Electrical Characteristics**

XC6219 series (Ta=25 $^{\circ}$ C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Output Voltage	Vout	Vin=Vout+1V 1.0mA≤ lout≤30mA	Vout×0.98		Vout×1.02	V
Output Current* 1	lout	Vin-Vout=1V		350		mA
Line Regulation	riangleVout1/ ( $ riangle$ Vin $\cdot$ Vout)	4.3V≤Vin≤8V lout=10mA		0.05	0.2	%/V
Load Regulation	△Vout	Vin= 4.3V 1.0mA≤ lout≤100mA		10	30	<sup>m</sup> V
Output voltage Temperature Coefficiency	△Vout/(Ta· Vout)	lout=30mA 0 C≤ Ta≤ 7 0 C		± 100		Ppm/ C
Supply Current	lss1			40	ŀ	uA
Input Voltage	Vin				8	V
PSRR	PSRR	F=1KHz, Vin=4.3Vdc+1Vpp		60		dB

# **TypicalApplicationCircuit**







## **Operational Explanation**

<Output Voltage Control>

The P-channel MOSFET is connected to the VOUT pin, driven by the subsequent output signal. The output voltage at the VOUT pin is controlled and stabilized by a system of negative feedback. The IC's internal circuitry can shut-down by the CE pin's signal

<Low ESR Capacitors>

With the XC6219 series, a stable output voltage is achievable even if used with low ESR capacitors as a phase compensation circuit is built-in. In order to ensure the effectiveness of the phase compensation, we suggest that an output capacitor (CL) is connected as close as possible to the output pin (VOUT) and the GND pin. Please use an output capacitor with a capacitance value of at least 10uF. Also, please connect an input capacitor (CIN) of 10uF between the VIN pin and the GND pin in order to ensure a stable power input. Stable phase compensation may not be ensured if the capacitor runs out capacitance when depending on bias and temperature. In case the capacitor depends on the bias and temperature, please make sure the capacitor can ensure the actual capacitance.

<CE Pin>

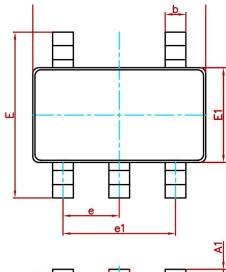
The IC's internal circuitry can be shutdown via the signal from the CE pin with the XC6219 series. The operational logic of the IC's CE pin is selectable (please refer to the selection guide). Although the CE pin is equal to an inverter input with CMOS hysteresis, with either the pull-up or pull-down options, the CE pin input current will increase when the IC is in operation. We suggest that you use this IC with either a VIN voltage or a VSS voltage input at the CE pin. If this IC is used with the correct specifications for the CE pin, the operational logic is fixed and the IC will operate normally. However, supply current may increase as a result of through current in the IC's internal circuitry.

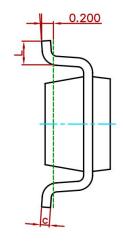
#### Notes on Use

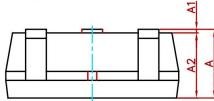
- 1. Please use this IC within the stated absolute maximum ratings. The IC is liable to malfunction should the ratings be exceeded.
- 2. Where wiring impedance is high, operations may become unstable due to noise and/or phase lag depending on output current. Please keep the resistance low between VIN and VSS wiring in particular.
- 3. Please wire the input capacitor (CIN) and the output capacitor (CL) as close to the IC as possible.



# **SOT-23-5 Package Outline Dimensions**

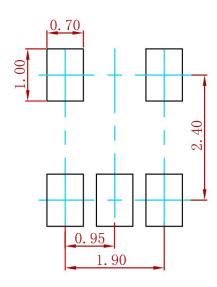






Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	1.050	1.250	0.041	0.049	
<b>A</b> 1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	2.650	2.950	0.104	0.116	
E1	1.500	1.700	0.059	0.067	
е	0.95	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	O°	8°	0°	8°	

# **SOT-23-5L Suggested Pad Layout**

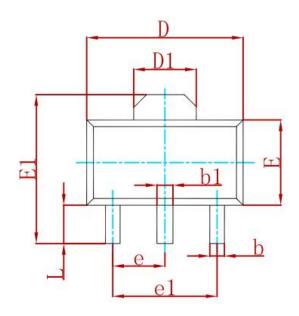


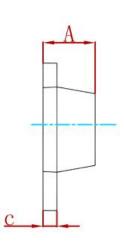
#### Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.



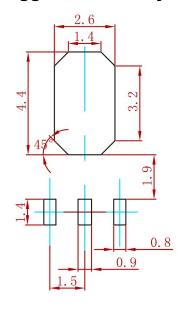
# **SOT-89 Package Outline Dimensions**





Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	1.400	1.600	0.055	0.063	
b	0.320	0.520	0.013	0.020	
b1	0.400	0.580	0.016	0.023	
С	0.350	0.440	0.014	0.017	
D	4.400	4.600	0.173	0.181	
D1	1.550	1.550 REF.		0.061 REF.	
Е	2.300	2.600	0.091	0.102	
E1	3.940	4.250	0.155	0.167	
е	1.500 TYP		0.060	TYP.	
e1	3.000 TYP .		0.118 TYP.		
L	0.900	1.200	0.035	0.047	

# **SOT-89 Suggested Pad Layout**



#### Note:

- 1. Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.



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